

Features

- Low power consumption
- Low voltage drop
- Low temperature coefficient
- High input voltage up to 30V
- Output voltage accuracy: tolerance $\pm 2\%$
- Over current protection
- Over temperature protection
- Chip enable/disable function
- 3-pin SOT89 and 5-pin SOT23 packages

Applications

- · Battery-powered equipment
- Communication equipment
- Audio/Video equipment

Selection Table

General Description

The HT75xx-7 is a low power high voltage series of regulators implemented in CMOS technology which has the advantages of low voltage drop and low quiescent current. They allow input voltages as high as 30V and are available with several fixed output voltages ranging from 2.1V to 12.0V.

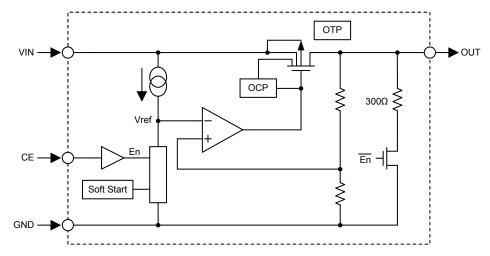
When the CE input is low, a fast discharge path pulls the output voltage low via an internal pull-down resistor. An internal over-current protection circuit prevents the device from damage even if the output is shorted to ground. An over-temperature protection circuit ensures the device junction temperature will not exceed a temperature of 160°C.

Part No.	Output Voltage	Packages	Markings
HT7521-7	2.1V		
HT7523-7	2.3V		
HT7525-7	2.5V		
HT7527-7	2.7V		
HT7530-7	3.0V		
HT7533-7	3.3V		
HT7536-7	3.6V		75xx-7 (for SOT89)
HT7540-7	4.0V	SOT89 SOT23-5	
HT7544-7	4.4V		5xx7 (for SOT23-5)
HT7550-7	5.0V		
HT7560-7	6.0V		
HT7570-7	7.0V		
HT7580-7	8.0V		
HT7590-7	9.0V		
HT75A0-7	10.0V		
HT75C0-7	12.0V		

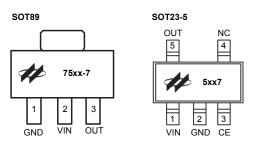
Note: "xx" stands for output voltages.



Block Diagram



Pin Assignment



Pin Descriptions

Pin No.		Pin Name	Pin Description	
SOT89	SOT23-5	Fill Name	Fill Description	
1	2	GND	Ground pin	
2	1	VIN	Input pin	
3	5	OUT	Output pin	
_	3	CE	Chip enable pin, high enable	
	4	NC	No connection	



Absolute Maximum Ratings

Parameter	Value	Unit	
V _{IN}		-0.3 to +33	V
V _{CE}	-0.3 to (V _{IN} +0.3)	V	
Operating Temperature Range, Ta		-40 to +85	°C
Maximum Junction Temperature, T _{J(MAX)}	+150	°C	
Storage Temperature Range	-65 to +165	°C	
	SOT89	200	°C/W
Junction-to-Ambient Thermal Resistance, θ _{JA} SOT23		500	°C/W
Dower Dissinction	SOT89	0.50	W
Power Dissipation, P _D	SOT23-5	0.20	W

Note: P_D is measured at Ta = 25°C.

Recommended Operating Range

Parameter	Value	Unit
V _{IN}	3.1 to 30	V
Vce	0 to V _{IN}	V

Electrical Characteristics

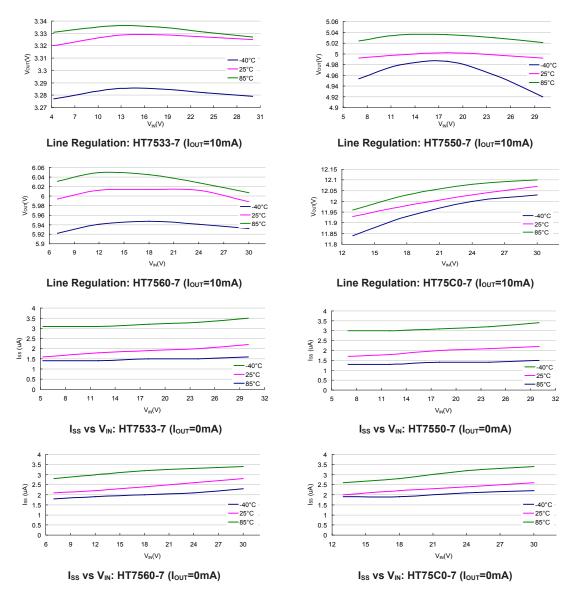
 $V_{\text{IN}}\text{=}V_{\text{OUT}}\text{+}2V,\,V_{\text{CE}}\text{=}V_{\text{IN}},\,\text{Ta}\text{=}\text{+}25^{\circ}\text{C}$ and $C_{\text{IN}}\text{=}C_{\text{OUT}}\text{=}10\mu\text{F},$ unless otherwise specified

Symbol	Parameter	Test Conditio	ons	Min.	Тур.	Max.	Unit
Vin	Input Voltage	_		_	_	30	V
Vout	Output Voltage Range	—		2.1	—	12.0	V
Vo	Output Voltage Accuracy	I _{OUT} =10mA		-2	_	2	%
	Output Current	V _{OUT} < 5.0V		100	—	_	mA
lout	Output Current	V _{OUT} ≥ 5.0V		150	—	—	mA
ΔVουτ	Load Regulation	1mA ≤ I _{OUT} ≤ 50mA			15	45	mV
VDIF	Dropout Voltage	Iout=1mA, Vout Change	e=2% (Note)	_	10	30	mV
I _{SS1}	Quiescent Current	I _{OUT} =0mA			2.5	4.0	μA
I _{SS2}		V _{CE} =2.0V, V _{IN} =30V, I _{OUT} =0mA		_	3.0	5.0	μA
I _{SHD}	Shutdown Current	V _{CE} =0V			0.1	0.5	μA
ΔVουτ	Line Deculation				0.1	0.2	%/V
$\overline{\Delta V_{\text{IN}} \times \Delta V_{\text{OUT}}}$	Line Regulation			_	0.2	0.4	%/V
$\frac{\Delta V_{\text{OUT}}}{\Delta T_{a} \times \Delta V_{\text{OUT}}}$	Temperature Coefficient	l _{оuт} =10mA, -40°С < Ta < 85°С		_	±100	_	ppm/°C
ISHORT	Output Short Current	V _{IN} =12V, force V _{OUT} =0V			150	—	mA
T _{SHD}	Shutdown Temperature				160	_	°C
TREC	Recovery Temperature	_			25	_	°C
VIH	Enable High Threshold	CE pin, V _{OUT} +1V ≤ V _{IN} ≤ 30V		2.0	_	_	V
VIL	Enable Low Threshold	CE pin, V _{OUT} +1V ≤ V _{IN} :	≤ 30V	_	_	0.6	V
R _{DIS}	Discharge Resistor	CE=0V, measure at Vo	UT	_	300	_	Ω

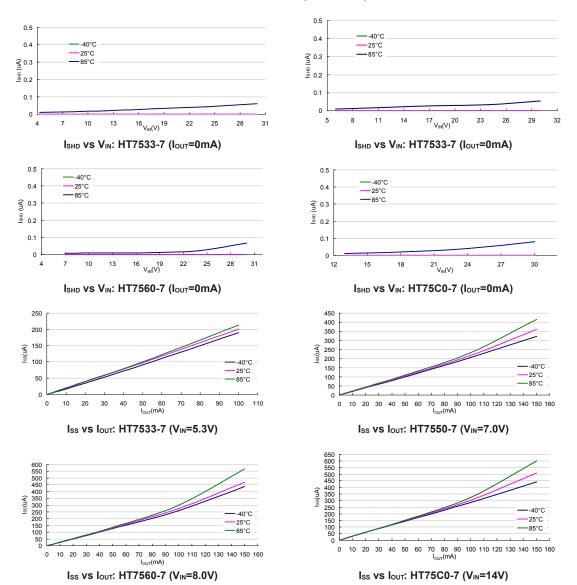
Note: The dropout voltage is defined as the input voltage minus the output voltage that produces a 2% change in the output voltage from the value at $V_{IN}=V_{OUT}+2V$ with a fixed load.



Typical Performance Characteristic

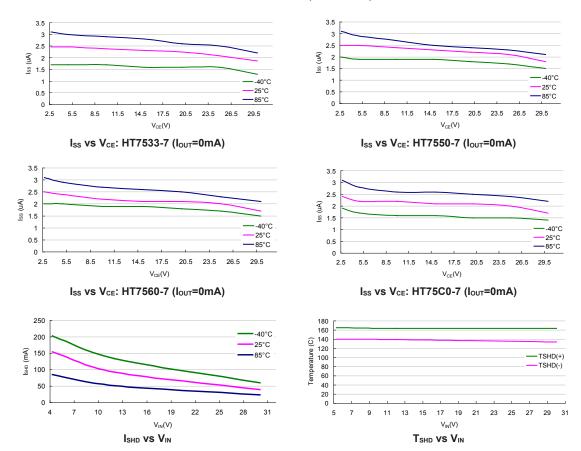




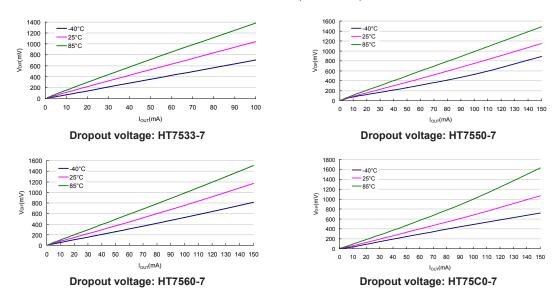


Test Condition: $V_{IN}=V_{OUT}+2V$, $V_{CE}=V_{IN}$, $I_{OUT}=10$ mA, $C_{IN}=10\mu$ F, $C_{OUT}=10\mu$ F and $Ta=25^{\circ}$ C, unless otherwise noted.

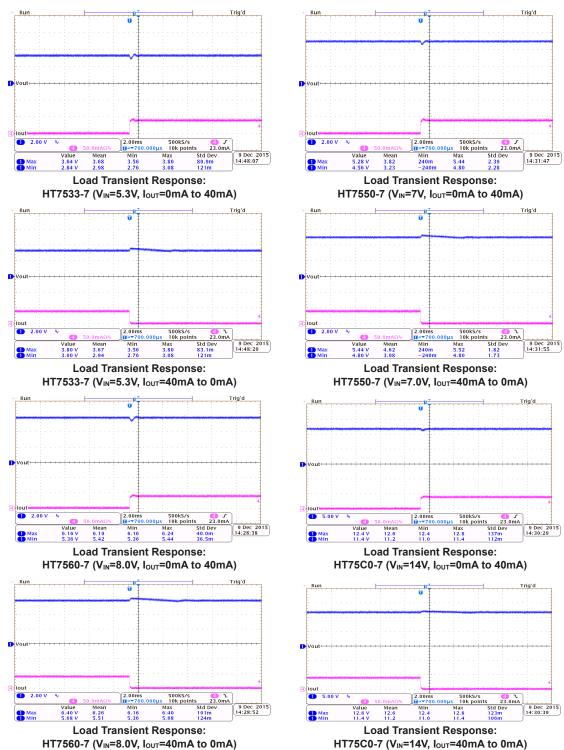




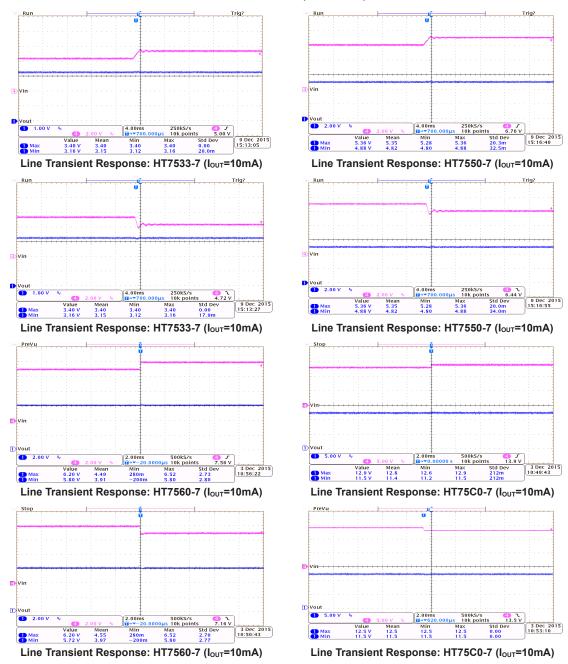




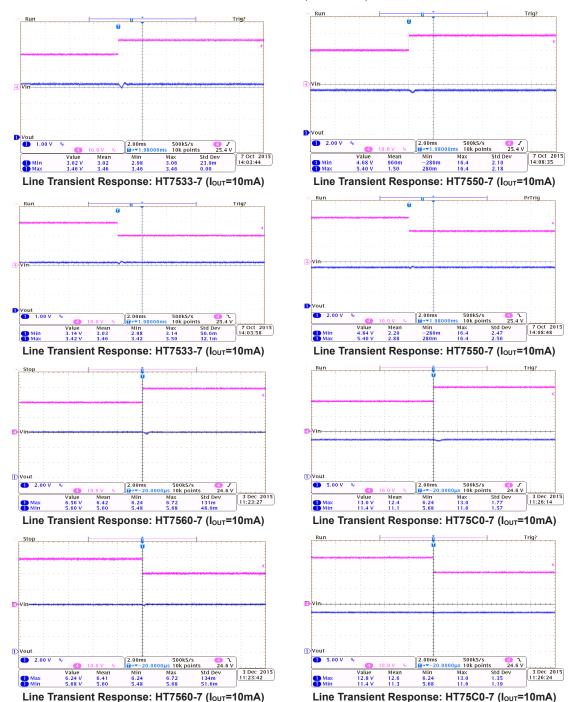






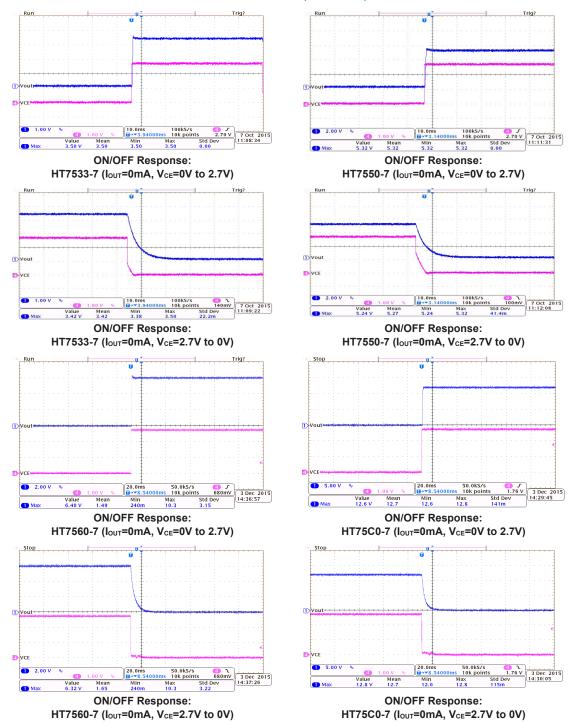




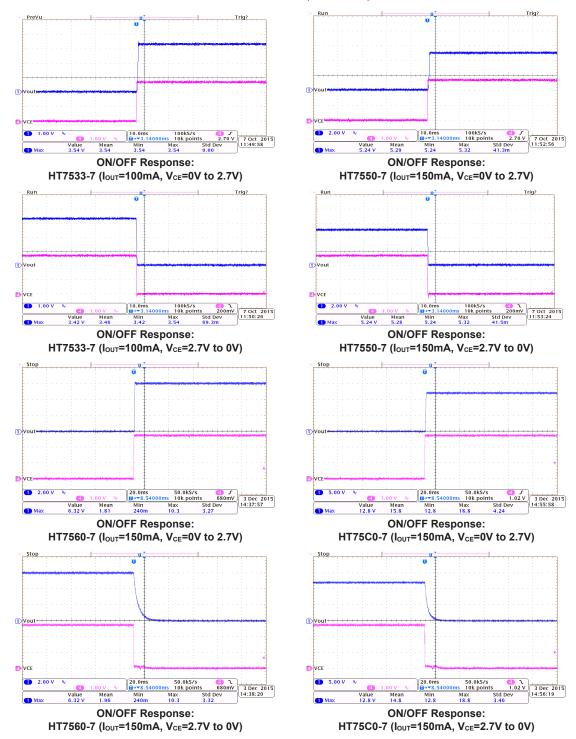






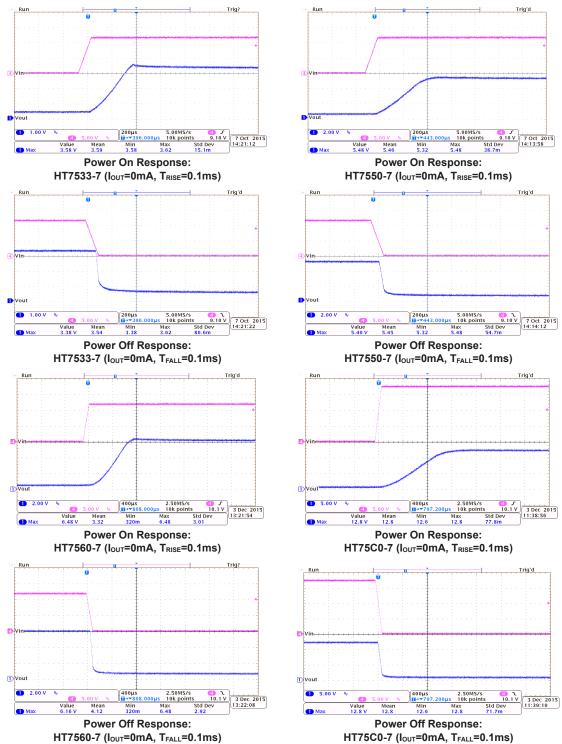




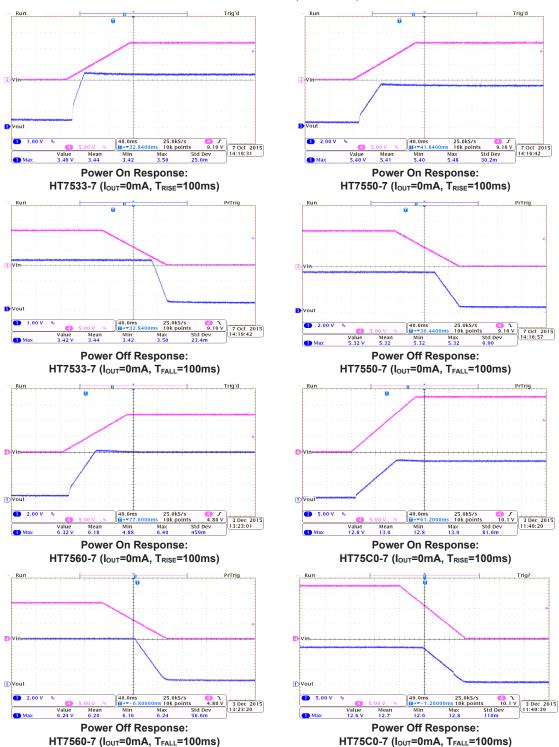






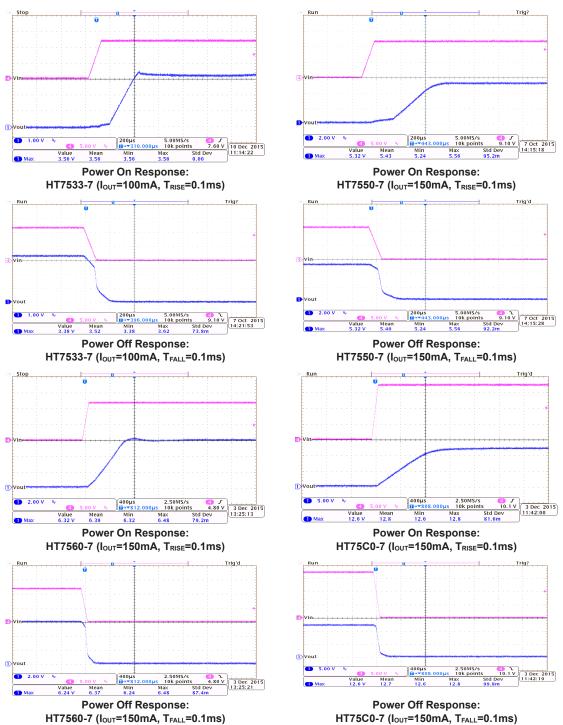






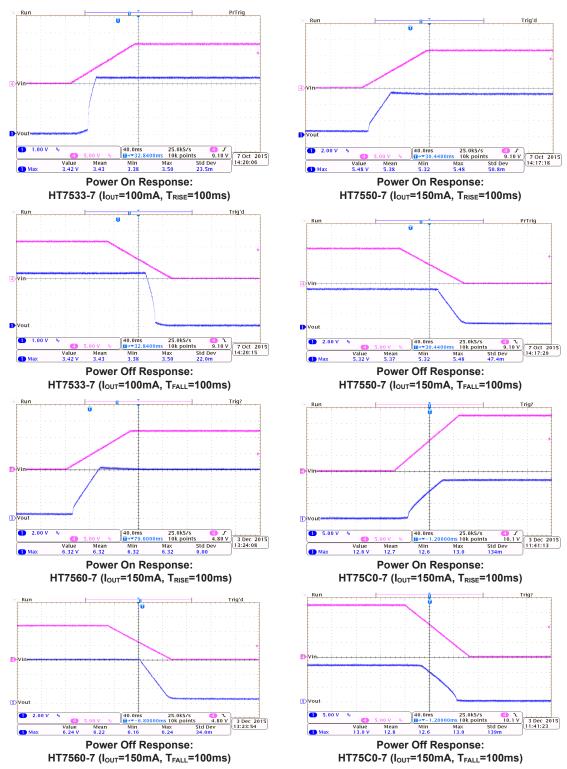
Test Condition: $V_{IN}=V_{OUT}+2V$, $V_{CE}=V_{IN}$, $I_{OUT}=10$ mA, $C_{IN}=10\mu$ F, $C_{OUT}=10\mu$ F and $Ta=25^{\circ}$ C, unless otherwise noted.





Test Condition: $V_{IN}=V_{OUT}+2V$, $V_{CE}=V_{IN}$, $I_{OUT}=10$ mA, $C_{IN}=10\mu$ F, $C_{OUT}=10\mu$ F and $Ta=25^{\circ}$ C, unless otherwise noted.







Application Information

When using the HT75xx-7 regulators, it is important that the following application points are noted if correct operation is to be achieved.

External Circuit

It is important that external capacitors are connected to both the input and output pins. For the input pin suitable bypass capacitors as shown in the application circuits should be connected especially in situations where a battery power source is used which may have a higher impedance. For the output pin, a suitable capacitor should also be connected especially in situations where the load is of a transient nature, in which case larger capacitor values should be selected to limit any output transient voltages.

Thermal Considerations

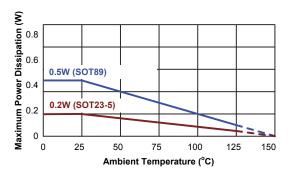
The maximum power dissipation depends on the thermal resistance of the package, the PCB layout, the rate of the surrounding airflow and the difference between the junction and ambient temperature. The maximum power dissipation can be calculated using the following formula:

$$P_{D(MAX)} = (T_{J(MAX)} - T_a) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_a is the ambient temperature and θ_{JA} is the junctionto-ambient thermal resistance of the IC package in degrees per watt. The following table shows the θ_{JA} values for various package types.

Package	θ _{JA} value °C/W
SOT89	200°C/W
SOT23-5	500°C/W

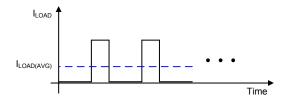
For maximum operating rating conditions, the maximum junction temperature is 150°C. However, it is recommended that the maximum junction temperature does not exceed 125°C during normal operation to maintain an adequate margin for device reliability. The derating curves of different packages for maximum power dissipation are as follows:



Power Dissipation Calculation

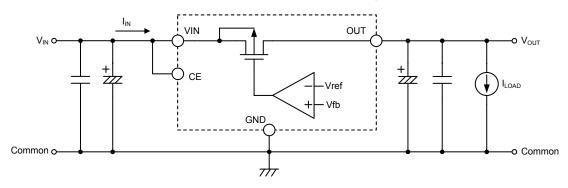
In order to keep the device within its operating limits and to maintain a regulated output voltage, the power dissipation of the device, given by P_D, must not exceed the Maximum Power Dissipation, given by P_{D(MAX)}. Therefore P_D \leq P_{D(MAX)}. From the diagram it can be seen that almost all of this power is generated across the pass transistor which is acting like a variable resistor in series with the load to keep the output voltage constant. This generated power which will appear as heat, must never allow the device to exceed its maximum junction temperature.

In practical applications the regulator may be called upon to provide both steady state and transient currents due to the transient nature of the load. Although the device may be working well within its limits with its steady state current, care must be taken with transient loads which may cause the current to rise close to its maximum current value. Care must be taken with transient loads and currents as this will result in device junction temperature rises which must not exceed the maximum junction temperature. With both steady state and transient currents, the important current to consider is the average or more precisely the RMS current which is the value of current that will appear as heat generated in the device. The following diagram shows how the average current relates to the transient currents.



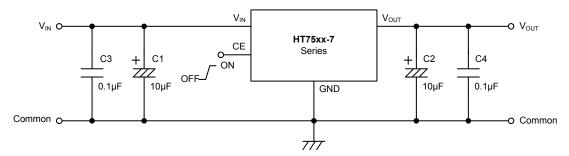


As the quiescent current of the device is very small it can generally be ignored and as a result the input current can be assumed to be equal to the output current. Therefore the power dissipation of the device, P_D , can be calculated as the voltage drop across the input and output multiplied by the current, given by the equation, $P_D = (V_{IN} - V_{OUT}) \times I_{IN}$. As the input current is also equal to the load current the power dissipation $P_D = (V_{IN} - V_{OUT}) \times I_{LOAD}$. However, with transient load currents, $P_D = (V_{IN} - V_{OUT}) \times I_{LOAD}(AVG)$ as shown in the figure.

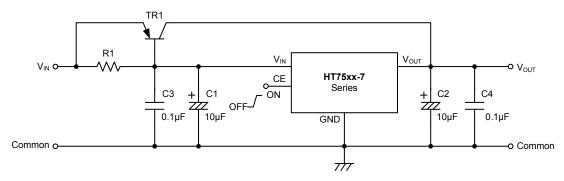


Application Circuits

Basic Circuits

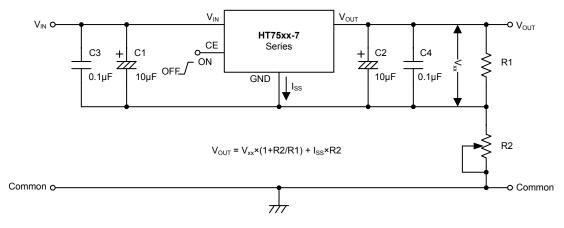


High Output Current Positive Voltage Regulator

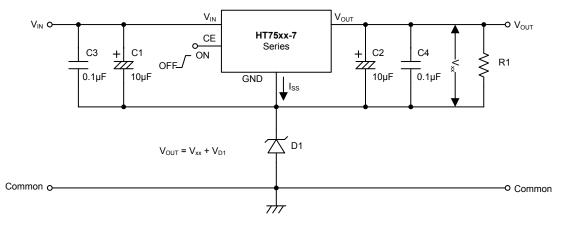




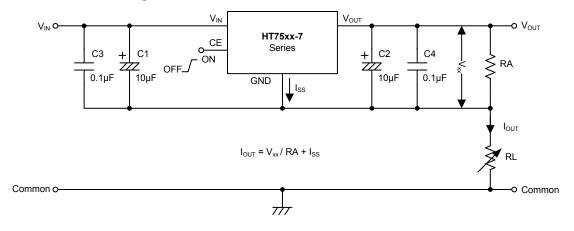
Circuit for Increasing Output Voltage



Circuit for Increasing Output Voltage

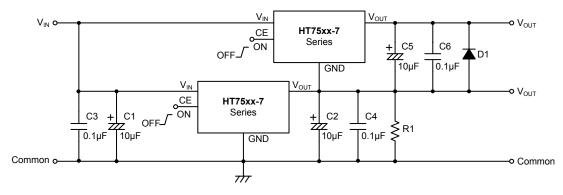


Constant Current Regulator





Dual Supply





Package Information

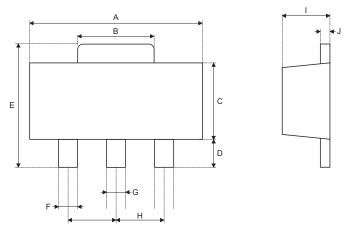
Note that the package information provided here is for consultation purposes only. As this information may be updated at regular intervals users are reminded to consult the <u>Holtek website</u> for the latest version of the <u>Package/</u> <u>Carton Information</u>.

Additional supplementary information with regard to packaging is listed below. Click on the relevant section to be transferred to the relevant website page.

- Further Package Information (include Outline Dimensions, Product Tape and Reel Specifications)
- Packing Meterials Information
- Carton information



3-pin SOT89 Outline Dimensions

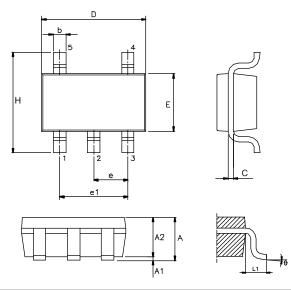


Symbol	Dimensions in inch			
	Min.	Nom.	Max.	
A	0.173	—	0.185	
В	0.053	_	0.072	
С	0.090	—	0.106	
D	0.031	—	0.047	
E	0.155	—	0.173	
F	0.014	—	0.019	
G	0.017	—	0.022	
Н	_	0.059 BSC	—	
I	0.055		0.063	
J	0.014	—	0.017	

Symbol	Dimensions in mm			
Symbol	Min.	Nom.	Max.	
A	4.40	—	4.70	
В	1.35	_	1.83	
С	2.29	—	2.70	
D	0.89	_	1.20	
E	3.94	—	4.40	
F	0.36	—	0.48	
G	0.44	_	0.56	
Н	—	1.50 BSC	—	
I	1.40	—	1.60	
J	0.35	—	0.44	



5-pin SOT23 Outline Dimensions



Symbol	Dimensions in inch			
Symbol	Min.	Nom.	Max.	
A	—	_	0.057	
A1	—	—	0.006	
A2	0.035	0.045	0.051	
b	0.012	_	0.020	
С	0.003	—	0.009	
D	—	0.114 BSC	_	
E	—	0.063 BSC	_	
е	—	0.037 BSC	_	
e1	—	0.075 BSC	_	
Н	—	0.110 BSC	_	
L1	_	0.024 BSC	_	
θ	0°	—	8°	

Symbol	Dimensions in mm			
Symbol	Min.	Nom.	Max.	
A	_	—	1.45	
A1	_	—	0.15	
A2	0.90	1.15	1.30	
b	0.30	—	0.50	
С	0.08	—	0.22	
D	_	2.90 BSC	_	
E	_	1.60 BSC	_	
е	_	0.95 BSC	_	
e1	—	1.90 BSC	_	
Н	—	2.80 BSC	_	
L1	_	0.60 BSC	_	
θ	0°	—	8°	

23

Copyright[©] 2018 by HOLTEK SEMICONDUCTOR INC.

The information appearing in this Data Sheet is believed to be accurate at the time of publication. However, Holtek assumes no responsibility arising from the use of the specifications described. The applications mentioned herein are used solely for the purpose of illustration and Holtek makes no warranty or representation that such applications will be suitable without further modification, nor recommends the use of its products for application that may present a risk to human life due to malfunction or otherwise. Holtek's products are not authorized for use as critical components in life support devices or systems. Holtek reserves the right to alter its products without prior notification. For the most up-to-date information, please visit our web site at http://www.holtek.com.tw.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LDO Voltage Regulators category:

Click to view products by Holtek manufacturer:

Other Similar products are found below :

AP7363-SP-13 L79M05TL-E AP7362-HA-7 PT7M8202B12TA5EX TCR3DF185,LM(CT TCR3DF45,LM(CT TLE4473G V52 059985X NCP4687DH15TIG 701326R NCV8170AXV250T2G SCD337BTG AP7315-25W5-7 AP2111H-1.2TRG1 ZLDO1117QK50TC AZ1117ID-ADJTRG1 TCR3DG12,LF MIC5514-3.3YMT-T5 SCD7912BTG NCP154MX180270TAG SCD33269T-5.0G NCV8170BXV330T2G NCV8170BMX330TCG NCV8170AMX120TCG NCP706ABMX300TAG NCP153MX330180TCG NCP114BMX075TCG MC33269T-3.5G CAT6243-ADJCMT5T TCR3DG33,LF TCR4DG35,LF TAR5S15U(TE85L,F) TAR5S18U(TE85L,F) TCR3UG19A,LF TCR4DG105,LF MPQ2013AGG-5-P NCV8170AMX360TCG TLE4268GSXUMA2 NCP715SQ15T2G MIC5317-3.0YD5-T5 NCV563SQ18T1G NCP715MX30TBG NCV8702MX25TCG NCV8170BXV120T2G MIC5317-1.2YD5-T5 NCV8170AMX150TCG NCV8170BMX150TCG AP2213D-3.3TRG1 NCV8170BMX120TCG NCV8170BMX310TCG